

TECHNICAL DATA DATA SHEET 4515, REV.-

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 150 VOLT, 30 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC LCC-3P PACKAGE.

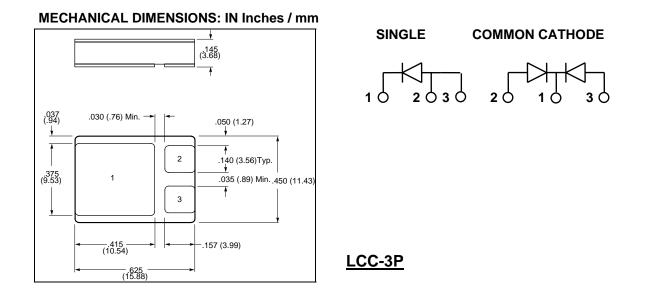
| AXIMUM RATINGS ALL RATINGS ARE $@T_c = 25 \degree C$ UNLESS OTHERWISE SPECIFIED. | | | | |
|---|------------------------|---------------------|-----------------|-------|
| RATING | | SYMBOL | MAX. | UNITS |
| PEAK INVERSE VOLTAGE | | PIV | 150 | Volts |
| MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ $T_c=100$ °C) (Single) | | Ι _Ο | 15 | Amps |
| MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ $T_c=100$ °C) (Common Cathode) | | Ι _Ο | 30 | Amps |
| MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine) | | I _{FSM} | 280 | Amps |
| MAXIMUM JUNCTION CAPACITANCE | (V _r =5V) | C _T | 500 | рF |
| MAXIMUM THERMAL RESISTANCE (Commor | (Single) n Cathode) | $R_{	ext{	heta}JC}$ | 1.21 0.61 | °C/W |
| MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE | | Top/Tstg | -65 to + 175 | °C |

ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | | | |
|--|----------------|------|-------|
| MAXIMUM FORWARD VOLTAGE DROP, Pulsed $(I_f = 15 \text{ Amps})$ | | | |
| T _J = 25 °C | V _f | 0.97 | Volts |
| T _J = 125 °C | | 0.81 | |
| MAXIMUM REVERSE CURRENT (Ir @ 150 V PIV) | | | |
| T _J = 25 °C | l _r | 0.5 | mA |
| T T_J = 125 °C | | 8 | |

SENSITRON SEMICONDUCTOR

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PINOUT TABLE

| DEVICE TYPE | PIN 1 | PIN 2 | PIN 3 |
|------------------|----------------|---------|---------|
| SINGLE RECTIFIER | CATHODE | ANODE | ANODE |
| COMMON CATHODE | COMMON CATHODE | ANODE 1 | ANODE 2 |



TECHNICAL DATA

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